

Welcome to **E-XFL.COM** 

**Understanding Embedded - DSP (Digital Signal Processors)** 

Embedded - DSP (Digital Signal Processors) are specialized microprocessors designed to perform complex mathematical computations on digital signals in real-time. Unlike general-purpose processors, DSPs are optimized for high-speed numeric processing tasks, making them ideal for applications that require efficient and precise manipulation of digital data. These processors are fundamental in converting and processing signals in various forms, including audio, video, and communication signals, ensuring that data is accurately interpreted and utilized in embedded systems.

Applications of <u>Embedded - DSP (Digital Signal Processors)</u>

Details	
Product Status	Obsolete
Туре	Fixed Point
Interface	CAN, EBI/EMI, I <sup>2</sup> C, IrDA, PPI, SPI, SPORT, UART/USART
Clock Rate	400MHz
Non-Volatile Memory	External
On-Chip RAM	68kB
Voltage - I/O	1.8V, 2.5V, 3.3V
Voltage - Core	1.29V
Operating Temperature	-40°C ~ 105°C (TA)
Mounting Type	Surface Mount
Package / Case	88-VFQFN Exposed Pad, CSP
Supplier Device Package	88-LFCSP-VQ (12x12)
Purchase URL	https://www.e-xfl.com/product-detail/analog-devices/adbf504wycpz401

Email: info@E-XFL.COM

Address: Room A, 16/F, Full Win Commercial Centre, 573 Nathan Road, Mongkok, Hong Kong

## **TABLE OF CONTENTS**

Peatures	Additional Information	21
Memory 1	Related Signal Chains	21
Peripherals	Signal Descriptions	22
General Description	Specifications	26
Portable Low-Power Architecture	Operating Conditions	26
System Integration	Electrical Characteristics	28
Processor Peripherals	Processor—Absolute Maximum Ratings	31
Blackfin Processor Core	ESD Sensitivity	32
Memory Architecture	Package Information	32
Flash Memory	Processor—Timing Specifications	33
DMA Controllers	Processor—Output Drive Currents	50
Watchdog Timer	Processor—Test Conditions	51
Timers	Processor—Environmental Conditions	53
Up/Down Counters and Thumbwheel Interfaces 10	Flash—Specifications	54
3-Phase PWM Units	Flash—Program and Erase Times and Endurance	
Serial Ports	Cycles	54
Serial Peripheral Interface (SPI) Ports	Flash—Absolute Maximum Ratings	54
UART Ports (UARTs)	ADC—Specifications	
Parallel Peripheral Interface (PPI) 11	ADC—Operating Conditions	55
RSI Interface	ADC—Timing Specifications	58
Controller Area Network (CAN) Interface	ADC—Absolute Maximum Ratings	58
TWI Controller Interface	ADC—Typical Performance Characteristics	59
Ports	ADC—Terminology	61
Dynamic Power Management	ADC—Theory of Operation	62
ADSP-BF50x Voltage Regulation	ADC—Modes of Operation	68
Clock Signals	ADC—Serial Interface	71
Booting Modes	120-Lead LQFP Lead Assignment	73
Instruction Set Description	88-Lead LFCSP Lead Assignment	76
Development Tools	Outline Dimensions	79
ADC and ACM Interface	Automotive Products	81
Internal ADC	Ordering Guide	81
ADC Application Hints		
REVISION HISTORY		
04/14—Rev. A to Rev. B	Revised package diagram (Figure 93) to include U-Groo	ve in
Jpdated Development Tools	Outline Dimensions	
Corrected RCKFE bit setting and description in	Package thickness changed from 0.75/0.80/0.85 to	
Table 9, The SPORTx Receive Configuration 1 Register	0.75/0.85/0.90 in Figure 94 in Outline Dimensions	79
SPORTx_RCR1)		
Jpdated footnote 6 in Operating Conditions		
Updated Table 18 with revised data for static Current—IDD-DEEPSLEEP (mA)		

Table 3. System Interrupt Controller (SIC)

Peripheral Interrupt Source	General-Purpose Interrupt (at Reset)	Peripheral Interrupt ID	Default Core Interrupt ID		SIC Registers
PLL Wakeup Interrupt	IVG7	0	0	IAR0	IMASKO, ISRO, IWRO
DMA Error (generic)	IVG7	1	0	IAR0	IMASKO, ISRO, IWRO
PPI Status	IVG7	2	0	IAR0	IMASKO, ISRO, IWRO
SPORT0 Status	IVG7	3	0	IAR0	IMASKO, ISRO, IWRO
SPORT1 Status	IVG7	4	0	IAR0	IMASKO, ISRO, IWRO
UARTO Status	IVG7	5	0	IAR0	IMASKO, ISRO, IWRO
UART1 Status	IVG7	6	0	IAR0	IMASKO, ISRO, IWRO
SPI0 Status	IVG7	7	0	IAR0	IMASKO, ISRO, IWRO
SPI1 Status	IVG7	8	0	IAR1	IMASKO, ISRO, IWRO
CAN Status	IVG7	9	0	IAR1	IMASKO, ISRO, IWRO
RSI Mask 0 Interrupt	IVG7	10	0	IAR1	IMASKO, ISRO, IWRO
Reserved	_	11	_	IAR1	IMASKO, ISRO, IWRO
CNT0 Interrupt	IVG8	12	1	IAR1	IMASKO, ISRO, IWRO
CNT1 Interrupt	IVG8	13	1	IAR1	IMASKO, ISRO, IWRO
DMA Channel 0 (PPI Rx/Tx)	IVG9	14	2	IAR1	IMASKO, ISRO, IWRO
DMA Channel 1 (RSI Rx/Tx)	IVG9	15	2	IAR1	IMASKO, ISRO, IWRO
DMA Channel 2 (SPORT0 Rx)	IVG9	16	2	IAR2	IMASKO, ISRO, IWRO
DMA Channel 3 (SPORT0 Tx)	IVG9	17	2	IAR2	IMASKO, ISRO, IWRO
DMA Channel 4 (SPORT1 Rx)	IVG9	18	2	IAR2	IMASKO, ISRO, IWRO
DMA Channel 5 (SPORT1 Tx)	IVG9	19	2	IAR2	IMASKO, ISRO, IWRO
DMA Channel 6 (SPI0 Rx/Tx)	IVG10	20	3	IAR2	IMASKO, ISRO, IWRO
DMA Channel 7 (SPI1 Rx/Tx)	IVG10	21	3	IAR2	IMASKO, ISRO, IWRO
DMA Channel 8 (UARTO Rx)	IVG10	22	3	IAR2	IMASKO, ISRO, IWRO
DMA Channel 9 (UART0 Tx)	IVG10	23	3	IAR2	IMASKO, ISRO, IWRO
DMA Channel 10 (UART1 Rx)	IVG10	24	3	IAR3	IMASKO, ISRO, IWRO
DMA Channel 11 (UART1 Tx)	IVG10	25	3	IAR3	IMASKO, ISRO, IWRO
CAN Receive	IVG11	26	4	IAR3	IMASKO, ISRO, IWRO
CAN Transmit	IVG11	27	4	IAR3	IMASKO, ISRO, IWRO
TWI	IVG11	28	4	IAR3	IMASKO, ISRO, IWRO
Port F Interrupt A	IVG11	29	4	IAR3	IMASKO, ISRO, IWRO
Port F Interrupt B	IVG11	30	4	IAR3	IMASKO, ISRO, IWRO
Reserved	_	31	_	IAR3	IMASKO, ISRO, IWRO
Timer 0	IVG12	32	5	IAR4	IMASK1, ISR1, IWR1
Timer 1	IVG12	33	5	IAR4	IMASK1, ISR1, IWR1
Timer 2	IVG12	34	5	IAR4	IMASK1, ISR1, IWR1
Timer 3	IVG12	35	5	IAR4	IMASK1, ISR1, IWR1
Timer 4	IVG12	36	5	IAR4	IMASK1, ISR1, IWR1
Timer 5	IVG12	37	5	IAR4	IMASK1, ISR1, IWR1
Timer 6	IVG12	38	5	IAR4	IMASK1, ISR1, IWR1
Timer 7	IVG12	39	5	IAR4	IMASK1, ISR1, IWR1
Port G Interrupt A	IVG12	40	5	IAR5	IMASK1, ISR1, IWR1
Port G Interrupt B	IVG12	41	5	IAR5	IMASK1, ISR1, IWR1
MDMA Stream 0	IVG13	42	6	IAR5	IMASK1, ISR1, IWR1

The timers can generate interrupts to the processor core providing periodic events for synchronization, either to the system clock or to a count of external signals.

In addition to the eight general-purpose programmable timers, a ninth timer is also provided. This extra timer is clocked by the internal processor clock and is typically used as a system tick clock for generation of operating system periodic interrupts.

# UP/DOWN COUNTERS AND THUMBWHEEL INTERFACES

Two 32-bit up/down counters are provided that can sense 2-bit quadrature or binary codes as typically emitted by industrial drives or manual thumbwheels. The counters can also operate in general-purpose up/down count modes. Then, count direction is either controlled by a level-sensitive input pin or by two edge detectors.

A third counter input can provide flexible zero marker support and can alternatively be used to input the push-button signal of thumb wheels. All three pins have a programmable debouncing circuit.

Internal signals forwarded to each timer unit enable these timers to measure the intervals between count events. Boundary registers enable auto-zero operation or simple system warning by interrupts when programmable count values are exceeded.

#### **3-PHASE PWM UNITS**

The two/dual 3-phase PWM generation units each feature:

- · 16-bit center-based PWM generation unit
- Programmable PWM pulse width
- Single/double update modes
- Programmable dead time and switching frequency
- Twos-complement implementation which permits smooth transition to full ON and full OFF states
- Possibility to synchronize the PWM generation to either externally-generated or internally-generated synchronization pulses
- Special provisions for BDCM operation (crossover and output enable functions)
- Wide variety of special switched reluctance (SR) operating modes
- Output polarity and clock gating control
- Dedicated asynchronous PWM shutdown signal

Each PWM block integrates a flexible and programmable 3-phase PWM waveform generator that can be programmed to generate the required switching patterns to drive a 3-phase voltage source inverter for ac induction motor (ACIM) or permanent magnet synchronous motor (PMSM) control. In addition, the PWM block contains special functions that considerably simplify the generation of the required PWM switching patterns for control of the electronically commutated motor (ECM) or brushless dc motor (BDCM). Software can enable a special mode for switched reluctance motors (SRM).

The six PWM output signals (per PWM unit) consist of three high-side drive signals (PWMx\_AH, PWMx\_BH, and PWMx\_CH) and three low-side drive signals (PWMx\_AL, PWMx\_BL, and PWMx\_CL). The polarity of the generated PWM signal can be set with software, so that either active HI or active LO PWM patterns can be produced.

The switching frequency of the generated PWM pattern is programmable using the 16-bit PWM\_TM register. The PWM generator can operate in single update mode or double update mode. In single update mode, the duty cycle values are programmable only once per PWM period, so that the resultant PWM patterns are symmetrical about the midpoint of the PWM period. In the double update mode, a second updating of the PWM registers is implemented at the midpoint of the PWM period. In this mode, it is possible to produce asymmetrical PWM patterns that produce lower harmonic distortion in 3-phase PWM inverters.

Pulses synchronous to the switching frequency can be generated internally and output on the PWMx\_SYNC pin. The PWM unit can also accept externally generated synchronization pulses through PWMx\_SYNC.

Each PWM unit features a dedicated asynchronous shutdown pin, PWMx\_TRIP, which (when brought low) instantaneously places all six PWM outputs in the OFF state.

#### **SERIAL PORTS**

The processors incorporate two dual-channel synchronous serial ports (SPORT0 and SPORT1) for serial and multiprocessor communications. The SPORTs support the following features:

- I<sup>2</sup>S capable operation.
- Bidirectional operation—Each SPORT has two sets of independent transmit and receive pins, enabling eight channels of I<sup>2</sup>S stereo audio.
- Buffered (8-deep) transmit and receive ports—Each port has a data register for transferring data words to and from other processor components and shift registers for shifting data in and out of the data registers.
- Clocking—Each transmit and receive port can either use an external serial clock or generate its own, in frequencies ranging from (f<sub>SCLK</sub>/131,070) Hz to (f<sub>SCLK</sub>/2) Hz.
- Word length—Each SPORT supports serial data words from 3 to 32 bits in length, transferred most significant bit first or least significant bit first.
- Framing—Each transmit and receive port can run with or without frame sync signals for each data word. Frame sync signals can be generated internally or externally, active high or low, and with either of two pulse widths and early or late frame sync.
- Companding in hardware—Each SPORT can perform
   A-law or μ-law companding according to ITU recommendation G.711. Companding can be selected on the transmit and/or receive channel of the SPORT without additional latencies.

where the variables in the equations are:

 $f_{CCLKNOM}$  is the nominal core clock frequency

 $f_{CCLKRED}$  is the reduced core clock frequency

 $V_{DDINTNOM}$  is the nominal internal supply voltage

 $V_{DDINTRED}$  is the reduced internal supply voltage

 $T_{NOM}$  is the duration running at  $f_{CCLKNOM}$ 

 $T_{RED}$  is the duration running at  $f_{CCLKRED}$ 

#### ADSP-BF50x VOLTAGE REGULATION

The ADSP-BF50x processors require an external voltage regulator to power the  $V_{\rm DDINT}$  domain. To reduce standby power consumption, the external voltage regulator can be signaled through EXT\_WAKE to remove power from the processor core. This signal is high-true for power-up and may be connected directly to the low-true shut-down input of many common regulators.

While in the hibernate state, all external supplies ( $V_{\rm DDEXT}$ ,  $V_{\rm DDFLASH}$ ) can still be applied, eliminating the need for external buffers. The external voltage regulator can be activated from this power down state by asserting the  $\overline{\rm RESET}$  pin, which then initiates a boot sequence. EXT\_WAKE indicates a wakeup to the external voltage regulator.

The power good  $(\overline{PG})$  input signal allows the processor to start only after the internal voltage has reached a chosen level. In this way, the startup time of the external regulator is detected after hibernation. For a complete description of the power good functionality, refer to the ADSP-BF50x Blackfin Processor Hardware Reference.

#### **CLOCK SIGNALS**

The processor can be clocked by an external crystal, a sine wave input, or a buffered, shaped clock derived from an external clock oscillator.

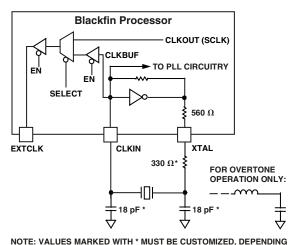
If an external clock is used, it should be a TTL-compatible signal and must not be halted, changed, or operated below the specified frequency during normal operation. This signal is connected to the processor's CLKIN pin. When an external clock is used, the XTAL pin must be left unconnected.

Alternatively, because the processor includes an on-chip oscillator circuit, an external crystal may be used. For fundamental frequency operation, use the circuit shown in Figure 4. A parallel-resonant, fundamental frequency, microprocessor-grade crystal is connected across the CLKIN and XTAL pins. The on-chip resistance between CLKIN and the XTAL pin is in the 500 k $\Omega$  range. Further parallel resistors are typically not recommended. The two capacitors and the series resistor shown in Figure 4 fine tune phase and amplitude of the sine frequency.

The capacitor and resistor values shown in Figure 4 are typical values only. The capacitor values are dependent upon the crystal manufacturers' load capacitance recommendations and the PCB physical layout. The resistor value depends on the drive level specified by the crystal manufacturer. The user should verify the customized values based on careful investigations on multiple devices over temperature range.

A third-overtone crystal can be used for frequencies above 25 MHz. The circuit is then modified to ensure crystal operation only at the third overtone by adding a tuned inductor circuit as shown in Figure 4. A design procedure for third-overtone operation is discussed in detail in (EE-168) Using Third Overtone Crystals with the ADSP-218x DSP on the Analog Devices website (www.analog.com)—use site search on "EE-168."

The Blackfin core runs at a different clock rate than the on-chip peripherals. As shown in Figure 5, the core clock (CCLK) and system peripheral clock (SCLK) are derived from the input clock (CLKIN) signal. An on-chip PLL is capable of multiplying the CLKIN signal by a programmable multiplication factor (bounded by specified minimum and maximum VCO frequencies). The default multiplier is 6×, but it can be modified by a software instruction sequence.



NOTE: VALUES MARKED WITH \* MUST BE CUSTOMIZED, DEPENDING ON THE CRYSTAL AND LAYOUT. PLEASE ANALYZE CAREFULLY. FOR FREQUENCIES ABOVE 33 MHz, THE SUGGESTED CAPACITOR VALUE OF 18 pF SHOULD BE TREATED AS A MAXIMUM, AND THE SUGGESTED RESISTOR VALUE SHOULD BE REDUCED TO 0  $\Omega$ .

Figure 4. External Crystal Connections

On-the-fly frequency changes can be effected by simply writing to the PLL\_DIV register. The maximum allowed CCLK and SCLK rates depend on the applied voltages  $V_{\rm DDINT}$  and  $V_{\rm DDEXT}$ ; the VCO is always permitted to run up to the CCLK frequency specified by the part's speed grade. The EXTCLK pin can be configured to output either the SCLK frequency or the input buffered CLKIN frequency, called CLKBUF. When configured to output SCLK (CLKOUT), the EXTCLK pin acts as a reference signal in many timing specifications. While active by default, it can be disabled using the EBIU\_AMGCTL register.

The ACM synchronizes the ADC conversion process; generating the ADC controls, the ADC conversion start signal, and other signals. The actual data acquisition from the ADC is done by the SPORT peripherals.

The serial interface on the ADC allows the part to be directly connected to the ADSP-BF504, ADSP-BF504F, and ADSP-BF506F processors using serial interface protocols.

Figure 6 shows how to connect an external ADC to the ACM and one of the two SPORTs on the ADSP-BF504 or ADSP-BF504F processors.

#### ADSP-BF504/ADSP-BF504F DRxSEC DRxPRI **SPORTX** RCLKx -RFSx SPORT SELECT ACLK MUX CS ACM\_A[2:0] ACM SGLDIFF ACM\_RANGE RANGE SGL/DIFF A[2:0] **ADC** $\overline{\mathsf{cs}}$ (EXTERNAL) **ADSCLK** $\mathbf{D}_{\mathbf{OUT}}\mathbf{A}$ $D_{OUT}B$

Figure 6. ADC (External), ACM, and SPORT Connections

The ADC is integrated into the ADSP-BF506F product. Figure 7 shows how to connect the internal ADC to the ACM and to one of the two SPORTs on the ADSP-BF506F processor.

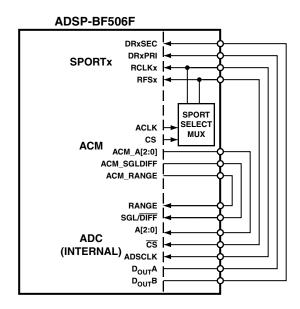


Figure 7. ADC (Internal), ACM, and SPORT Connections

The ADSP-BF504, ADSP-BF504F, and ADSP-BF506F processors interface directly to the ADC without any glue logic required. The availability of secondary receive registers on the serial ports of the Blackfin processors means only one serial port is necessary to read from both  $D_{\rm OUT}$  pins simultaneously. Figure 7 (ADC (Internal), ACM, and SPORT Connections) shows both  $D_{\rm OUT}A$  and  $D_{\rm OUT}B$  of the ADC connected to one of the processor's serial ports. The SPORTx Receive Configuration 1 register and SPORTx Receive Configuration 2 register should be set up as outlined in Table 9 (The SPORTx Receive Configuration 1 Register (SPORTx\_RCR1)) and Table 10 (The SPORTx Receive Configuration 2 Register (SPORTx\_RCR2)).

Table 9. The SPORTx Receive Configuration 1 Register (SPORTx\_RCR1)

Setting	Description
RCKFE = 0	Sample data with falling edge of RSCLK
LRFS = 1	Active low frame signal
RFSR = 1	Frame every word
IRFS = 0	External RFS used
RLSBIT = 0	Receive MSB first
RDTYPE = 00	Zero fill
IRCLK = 0	External receive clock
RSPEN = 1	Receive enabled
TFSR = RFSR = 1	

Table 12. ADC—Signal Descriptions (ADSP-BF506F Processor Only) (Continued)

Signal Name	Туре	Function
D <sub>OUT</sub> A, D <sub>OUT</sub> B	0	Serial Data Outputs. The data output is supplied to each pin as a serial data stream. The bits are clocked out on the falling edge of the ADSCLK input and 14 ADSCLKs are required to access the data. The data simultaneously appears on both pins from the simultaneous conversions of both ADCs. The data stream consists of two leading zeros followed by the 12 bits of conversion data. The data is provided MSB first. If $\overline{CS}$ is held low for 16 ADSCLK cycles rather than 14, then two trailing zeros will appear after the 12 bits of data. If $\overline{CS}$ is held low for a further 16 ADSCLK cycles on either $D_{OUT}A$ or $D_{OUT}B$ , the data from the other ADC follows on the $D_{OUT}$ pin. This allows data from a simultaneous conversion on both ADCs to be gathered in serial format on either $D_{OUT}A$ or $D_{OUT}B$ using only one serial port. For more information, see the ADC—Serial Interface section.
V <sub>DRIVE</sub>	Р	Logic Power Supply Input. The voltage supplied at this pin determines at what voltage the digital I/O interface operates. This pin should be decoupled to DGND. The voltage at this pin may be different than that at $AV_{DD}$ and $DV_{DD}$ but should never exceed either by more than 0.3 V.
$DV_DD$	Р	Digital Supply Voltage, 2.7 V to 5.25 V. This is the supply voltage for all digital circuitry on the internal ADC. The DV <sub>DD</sub> and AV <sub>DD</sub> voltages should ideally be at the same potential and must not be more than 0.3 V apart even on a transient basis. This supply should be decoupled to DGND.

### ADSP-BF50x Clock Related Operating Conditions

Table 14 describes the core clock timing requirements for the ADSP-BF50x processors. Take care in selecting MSEL, SSEL, and CSEL ratios so as not to exceed the maximum core clock and system clock (see Table 16). Table 15 describes phase-locked loop operating conditions.

Table 14. Core Clock (CCLK) Requirements—ADSP-BF50x Processors—All Speed Grades

				Max CCLK	
Paramete	•	Min V <sub>DDINT</sub>	Nom V <sub>DDINT</sub>	Frequency	Unit
$f_{CCLK}$	Core Clock Frequency (All Models)	1.33 V	1.400 V	400	MHz
	Core Clock Frequency (Industrial/Commercial Models)	1.16 V	1.225 V	300	MHz
	Core Clock Frequency (Industrial Models Only)	1.14 V	1.200 V	200	MHz
	Core Clock Frequency (Commercial Models Only)	1.10 V	1.150 V	200	MHz

Table 15. Phase-Locked Loop Operating Conditions

Parameter		Min	Max	Unit
f <sub>VCO</sub>	Voltage Controlled Oscillator (VCO) Frequency (Commercial/Industrial Models)	72	Instruction Rate <sup>1</sup>	MHz
	Voltage Controlled Oscillator (VCO) Frequency (Automotive Models)	84	Instruction Rate <sup>1</sup>	MHz

<sup>&</sup>lt;sup>1</sup> For more information, see Ordering Guide on Page 81.

Table 16. Maximum SCLK Conditions for ADSP-BF50x Processors

Parameter		V <sub>DDEXT</sub> = 1.8 V/2.5 V/3.3 V Nominal	Unit
$f_{\text{SCLK}}$	CLKOUT/SCLK Frequency (V <sub>DDINT</sub> ≥ 1.16 V)	100	MHz
	CLKOUT/SCLK Frequency (V <sub>DDINT</sub> < 1.16 V)	80	MHz

### **ELECTRICAL CHARACTERISTICS**

Parameter		Test Conditions	Min	Typical	Max	Unit
V <sub>OH</sub>	High Level Output Voltage	$V_{DDEXT} = 1.7 \text{ V, } I_{OH} = -0.5 \text{ mA}$	1.35			٧
	High Level Output Voltage	$V_{DDEXT} = 2.25 \text{ V, } I_{OH} = -0.5 \text{ mA}$	2.0			V
	High Level Output Voltage	$V_{DDEXT} = 3.0 \text{ V, } I_{OH} = -0.5 \text{ mA}$	2.4			V
$V_{OL}$	Low Level Output Voltage	$V_{DDEXT} = 1.7 \text{ V/2.25 V/3.0 V},$ $I_{OL} = 2.0 \text{ mA}$			0.4	V
I <sub>IH</sub>	High Level Input Current <sup>1</sup>	$V_{DDEXT} = 3.6 \text{ V}, V_{IN} = 3.6 \text{ V}$			10.0	μΑ
I <sub>IL</sub>	Low Level Input Current <sup>1</sup>	$V_{DDEXT} = 3.6 \text{ V}, V_{IN} = 0 \text{ V}$			10.0	μΑ
$I_{IHP}$	High Level Input Current JTAG <sup>2</sup>	$V_{DDEXT} = 3.6 \text{ V}, V_{IN} = 3.6 \text{ V}$			75.0	μΑ
I <sub>OZH</sub>	Three-State Leakage Current <sup>3</sup>	$V_{DDEXT} = 3.6 \text{ V}, V_{IN} = 3.6 \text{ V}$			10.0	μΑ
I <sub>OZHTWI</sub>	Three-State Leakage Current <sup>4</sup>	$V_{DDEXT} = 3.0 \text{ V}, V_{IN} = 5.5 \text{ V}$			10.0	μΑ
I <sub>OZL</sub>	Three-State Leakage Current <sup>3</sup>	$V_{DDEXT} = 3.6 \text{ V}, V_{IN} = 0 \text{ V}$			10.0	μΑ
$C_IN$	Input Capacitance <sup>5,6</sup>	$ \begin{aligned} f_{\text{IN}} &= 1 \text{ MHz, } T_{\text{AMBIENT}} = 25^{\circ}\text{C,} \\ V_{\text{IN}} &= 2.5 \text{ V} \end{aligned} $		5	8	pF
$C_{\text{INTWI}}$	Input Capacitance <sup>4,6</sup>	$f_{IN} = 1 \text{ MHz}, T_{AMBIENT} = 25^{\circ}\text{C},$ $V_{IN} = 2.5 \text{ V}$			10	pF
I <sub>DDDEEPSLEEP</sub> <sup>7</sup>	V <sub>DDINT</sub> Current in Deep Sleep Mode	$V_{DDINT} = 1.2 \text{ V}, f_{CCLK} = 0 \text{ MHz}, \\ f_{SCLK} = 0 \text{ MHz}, T_{J} = 25^{\circ}\text{C}, \\ ASF = 0.00$		1.85		mA
I <sub>DDSLEEP</sub>	V <sub>DDINT</sub> Current in Sleep Mode	$V_{DDINT} = 1.2 \text{ V, } f_{SCLK} = 25 \text{ MHz,} $ $T_{J} = 25^{\circ}\text{C}$		2.1		mA
I <sub>DD-IDLE</sub>	V <sub>DDINT</sub> Current in Idle	$V_{DDINT} = 1.2 \text{ V, } f_{CCLK} = 50 \text{ MHz,}$ $T_J = 25^{\circ}\text{C, ASF} = 0.42$		18		mA
I <sub>DD-TYP</sub>	V <sub>DDINT</sub> Current	$V_{DDINT} = 1.40 \text{ V}, f_{CCLK} = 400 \text{ MHz}, $ $T_{J} = 25 ^{\circ}\text{C}, \text{ ASF} = 1.00$		104		mA
	V <sub>DDINT</sub> Current	$V_{DDINT} = 1.225 \text{ V}, f_{CCLK} = 300 \text{ MHz}, $ $T_J = 25^{\circ}\text{C}, \text{ ASF} = 1.00$		69		mA
	V <sub>DDINT</sub> Current	$V_{DDINT} = 1.2 \text{ V, } f_{CCLK} = 200 \text{ MHz,}$ $T_J = 25 ^{\circ}\text{C, ASF} = 1.00$		51		mA
I <sub>DDHIBERNATE</sub> <sup>8</sup>	Hibernate State Current	$\begin{split} &V_{DDEXT}\!=3.30 \text{ V,} \\ &V_{DDFLASH}\!=\!1.8 \text{ V,}        $		40		μΑ
I <sub>DDSLEEP</sub> <sup>9</sup>	V <sub>DDINIT</sub> Current in Sleep Mode	$f_{CCLK} = 0 \text{ MHz}, f_{SCLK} > 0 \text{ MHz}$			Table 18 + $(.16 \times V_{DDINT} \times f_{SCLK})$	mA <sup>10</sup>
I <sub>DDDEEPSLEEP</sub> 9	V <sub>DDINT</sub> Current in Deep Sleep Mode	$f_{CCLK} = 0 \text{ MHz}, f_{SCLK} = 0 \text{ MHz}$			Table 18	mA
I <sub>DDINT</sub> <sup>9</sup>	V <sub>DDINT</sub> Current	$f_{CCLK} > 0 \text{ MHz}, f_{SCLK} \ge 0 \text{ MHz}$			Table 18 + $(Table 19 \times ASF) + (.16 \times V_{DDINT} \times f_{SCLK})$	mA
I <sub>DDFLASH1</sub>	Flash Memory Supply Current 1 — Asynchronous Read (5 MHz NORCLK <sup>11</sup> )			10	20	mA
	Flash Memory Supply Current 1	4 Word		18	20	mA
	— Synchronous Read (50 MHz	8 Word		20	22	mA
	NORCLK <sup>11</sup> )	16 Word		25	27	mA
		Continuous		28	30	mA

Parameter	r	<b>Test Conditions</b>	Min	Typical	Max	Unit
I <sub>DDFLASH2</sub>	Flash Memory Supply Current 2 — Reset/Powerdown			15	50	μΑ
I <sub>DDFLASH3</sub>	Flash Memory Supply Current 3 — Standby			15	50	μΑ
I <sub>DDFLASH4</sub>	Flash Memory Supply Current 4 — Automatic Standby			15	50	μΑ
I <sub>DDFLASH5</sub>	Flash Memory Supply Current 5 — Program			15	40	mA
	Flash Memory Supply Current 5 — Erase			15	40	mA
I <sub>DDFLASH6</sub>	Flash Memory Supply Current 6 — Dual Operations	Program/Erase in one bank, asynchronous read in another bank		25	60	mA
		Program/Erase in one bank, synchronous read in another bank		43	70	mA
I <sub>DDFLASH7</sub>	Flash Memory Supply Current 7 — Program/Erase Suspended (Standby)			15	50	μΑ

<sup>&</sup>lt;sup>1</sup> Applies to input pins.

 $<sup>^2</sup>$  Applies to JTAG input pins (TCK, TDI, TMS,  $\overline{\text{TRST}}\text{)}.$ 

<sup>&</sup>lt;sup>3</sup> Applies to three-statable pins.

<sup>&</sup>lt;sup>4</sup> Applies to bidirectional pins SCL and SDA.

<sup>&</sup>lt;sup>5</sup> Applies to all signal pins, except SCL and SDA.

<sup>&</sup>lt;sup>6</sup>Guaranteed, but not tested.

<sup>&</sup>lt;sup>7</sup> See the ADSP-BF50x Blackfin Processor Hardware Reference Manual for definition of sleep, deep sleep, and hibernate operating modes.

 $<sup>^8</sup>$  Applies to  $V_{\mbox{\scriptsize DDEXT}}$  supply only. Clock inputs are tied high or low.

<sup>&</sup>lt;sup>9</sup>Guaranteed maximum specifications.

 $<sup>^{10}</sup>$ Unit for  $V_{DDINT}$  is V (Volts). Unit for  $f_{SCLK}$  is MHz. Example: 1.4 V, 75 MHz would be  $0.16 \times 1.4 \times 75 = 16.8$  mA adder.

 $<sup>^{11}\</sup>mbox{See}$  the ADSP-BF50x Blackfin Processor Hardware Reference Manual for definition of NORCLK.

#### **ESD SENSITIVITY**



### ESD (electrostatic discharge) sensitive device.

Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

#### **PACKAGE INFORMATION**

The information presented in Figure 9 and Table 23 provides details about the package branding for the ADSP-BF50x processors.



Figure 9. Product Information on Package

Table 23. Package Brand Information<sup>1</sup>

Brand Key	Field Description
ADSP-BF50x	Product Name <sup>2</sup>
t	Temperature Range
рр	Package Type
Z	RoHS Compliant Designation
ccc	See Ordering Guide
VVVVV.X	Assembly Lot Code
n.n	Silicon Revision
#	RoHS Compliance Designator
yyww	Date Code

<sup>&</sup>lt;sup>1</sup> Nonautomotive only. For branding information specific to Automotive products, contact Analog Devices Inc.

<sup>&</sup>lt;sup>2</sup> See product names in the Ordering Guide on Page 81.

### **Parallel Peripheral Interface Timing**

Table 27 and Figure 14 on Page 35, Figure 20 on Page 40, and Figure 22 on Page 41 describe parallel peripheral interface operations.

Table 27. Parallel Peripheral Interface Timing

			$I_{\text{DDEXT}} = 1.8 \text{ V}$	<b>V</b> <sub>DDE</sub>	$_{\rm EXT} = 2.5 \text{ V}/3.3 \text{ V}$	
Paramete	r	Min	Max	Min	Max	Unit
Timing Red	quirements					
$t_{PCLKW}$	PPI_CLK Width <sup>1</sup>	t <sub>SCLK</sub> – 1.5	5	t <sub>SCLK</sub> – 1.5	5	ns
$t_{PCLK}$	PPI_CLK Period <sup>1</sup>	$2 \times t_{SCLK}$	-1.5	$2 \times t_{SCLK}$	-1.5	ns
Timing Red	quirements—GP Input and Frame Capture Modes					
$t_{PSUD}$	External Frame Sync Startup Delay <sup>2</sup>	$4 \times t_{PCLK}$		$4 \times t_{PCLK}$		ns
t <sub>SFSPE</sub>	External Frame Sync Setup Before PPI_CLK (Nonsampling Edge for Rx, Sampling Edge for Tx)	6.7		6.7		ns
t <sub>HFSPE</sub>	External Frame Sync Hold After PPI_CLK	1.5		1.5		ns
$t_{\text{SDRPE}}$	Receive Data Setup Before PPI_CLK	4.1		3.5		ns
$t_{\text{HDRPE}}$	Receive Data Hold After PPI_CLK	2		1.6		ns
Switching	Characteristics—GP Output and Frame Capture Modes					
t <sub>DFSPE</sub>	Internal Frame Sync Delay After PPI_CLK		8.7		8.0	ns
t <sub>HOFSPE</sub>	Internal Frame Sync Hold After PPI_CLK	1.7		1.7		ns
t <sub>DDTPE</sub>	Transmit Data Delay After PPI_CLK		8.7		8.0	ns
t <sub>HDTPE</sub>	Transmit Data Hold After PPI_CLK	2.3		1.9		ns

<sup>&</sup>lt;sup>1</sup> PPI\_CLK frequency cannot exceed f<sub>SCLK</sub>/2

<sup>&</sup>lt;sup>2</sup> The PPI port is fully enabled 4 PPI clock cycles after the PAB write to the PPI port enable bit. Only after the PPI port is fully enabled are external frame syncs and data words guaranteed to be received correctly by the PPI peripheral.

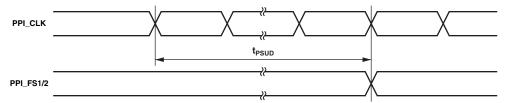


Figure 13. PPI with External Frame Sync Timing

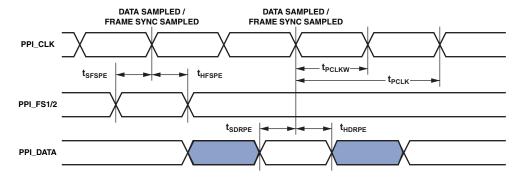


Figure 14. PPI GP Rx Mode with External Frame Sync Timing

### **RSI Controller Timing**

Table 28 and Figure 18 describe RSI Controller Timing. Table 29 and Figure 19 describe RSI controller (high speed) timing.

### Table 28. RSI Controller Timing

Parar	meter	Min	Max	Unit
Timin	Timing Requirements			
$t_{ISU}$	Input Setup Time	5.75		ns
$t_IH$	Input Hold Time	2		ns
Switc	hing Characteristics			
$f_{PP}^{-1}$	Clock Frequency Data Transfer Mode	0	25	MHz
$f_{OD}$	Clock Frequency Identification Mode	100 <sup>2</sup>	400	kHz
$t_WL$	Clock Low Time	10		ns
$t_{WH}$	Clock High Time	10		ns
$t_{TLH}$	Clock Rise Time		10	ns
$t_{THL}$	Clock Fall Time		10	ns
$t_{ODLY}$	Output Delay Time During Data Transfer Mode		14	ns
t <sub>ODLY</sub>	Output Delay Time During Identification Mode		50	ns

 $<sup>^{1}\,</sup>t_{_{PP}}=1/f_{_{PP}}.$ 

<sup>&</sup>lt;sup>2</sup> Specification can be 0 kHz, which means to stop the clock. The given minimum frequency range is for cases where a continuous clock is required.

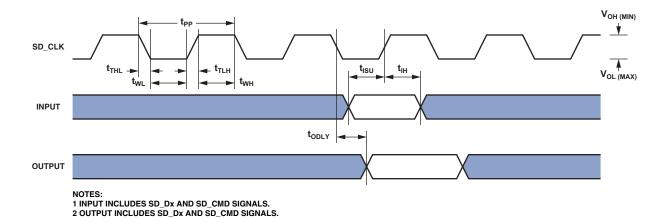
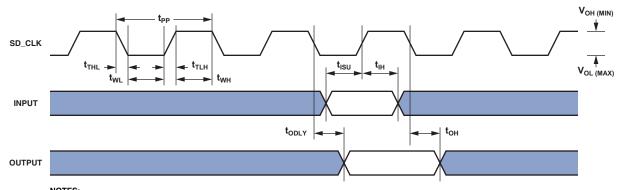


Figure 18. RSI Controller Timing

Table 29. RSI Controller Timing (High Speed Mode)

Parar	Parameter		Max	Unit
Timin	g Requirements			
$t_{ISU}$	Input Setup Time	5.75		ns
$t_{\text{IH}}$	Input Hold Time	2		ns
Switch	ning Characteristics			
$f_{PP}^{-1}$	Clock Frequency Data Transfer Mode	0	50	MHz
$t_WL$	Clock Low Time	7		ns
$t_{WH}$	Clock High Time	7		ns
$t_{TLH}$	Clock Rise Time		3	ns
$t_{THL}$	Clock Fall Time		3	ns
$t_{\text{ODLY}}$	Output Delay Time During Data Transfer Mode		2.5	ns
t <sub>OH</sub>	Output Hold Time	2.5		ns

 $<sup>^{1}</sup>$   $t_{pp} = 1/f_{pp}$ .



NOTES: 1 INPUT INCLUDES SD\_Dx AND SD\_CMD SIGNALS. 2 OUTPUT INCLUDES SD\_Dx AND SD\_CMD SIGNALS.

Figure 19. RSI Controller Timing (High-Speed Mode)

#### **Serial Ports**

Table 30 through Table 33 on Page 41 and Figure 20 on Page 40 through Figure 22 on Page 41 describe serial port operations.

Table 30. Serial Ports—External Clock

		V	7 <sub>DDEXT</sub> = 1.8 V	V <sub>DDEX</sub>	<sub>T</sub> = 2.5 V/3.3 V	
Parameter		Min	Max	Min	Max	Unit
Timing Re	quirements					
t <sub>SFSE</sub>	TFSx/RFSx Setup Before TSCLKx/RSCLKx <sup>1</sup>	3.0		3.0		ns
t <sub>HFSE</sub>	TFSx/RFSx Hold After TSCLKx/RSCLKx <sup>1</sup>	3.0		3.0		ns
t <sub>SDRE</sub>	Receive Data Setup Before RSCLKx <sup>1,2</sup>	3.0		3.0		ns
$t_{\text{HDRE}}$	Receive Data Hold After RSCLKx <sup>1,2</sup>	3.5		3.0		ns
t <sub>SCLKEW</sub>	TSCLKx/RSCLKx Width	4.5		4.5		ns
t <sub>SCLKE</sub>	TSCLKx/RSCLKx Period	$2 \times t_{SCLK}$		$2 \times t_{SCLK}$		ns
Switching	Characteristics					
t <sub>DFSE</sub>	TFSx/RFSx Delay After TSCLKx/RSCLKx (Internally Generated TFSx/RFSx) <sup>3</sup>		10.0		10.0	ns
t <sub>HOFSE</sub>	TFSx/RFSx Hold After TSCLKx/RSCLKx (Internally Generated TFSx/RFSx) <sup>3</sup>	0.0		0.0		ns
t <sub>DDTE</sub>	Transmit Data Delay After TSCLKx <sup>3</sup>		11.0		10.0	ns
t <sub>HDTE</sub>	Transmit Data Hold After TSCLKx <sup>3</sup>	0.0		0.0		ns

<sup>&</sup>lt;sup>1</sup> Referenced to sample edge.

Table 31. Serial Ports—Internal Clock

		v	$V_{\text{DDEXT}} = 1.8 \text{ V}$	$V_{\text{ddex}}$	$_{T}$ = 2.5 V/3.3 V	
Parameter		Min	Max	Min	Max	Unit
Timing Red	quirements					
$t_{SFSI}$	TFSx/RFSx Setup Before TSCLKx/RSCLKx <sup>1</sup>	11.0		9.6		ns
t <sub>HFSI</sub>	TFSx/RFSx Hold After TSCLKx/RSCLKx <sup>1</sup>	-1.5		-1.5		ns
$t_{\text{SDRI}}$	Receive Data Setup Before RSCLKx <sup>1,2</sup>	11.5		10.0		ns
$t_{HDRI}$	Receive Data Hold After RSCLKx <sup>1,2</sup>	-1.5		-1.5		ns
Switching	Characteristics					
t <sub>SCLKIW</sub>	TSCLKx/RSCLKx Width	7.0		8.0		ns
t <sub>DFSI</sub>	TFSx/RFSx Delay After TSCLKx/RSCLKx (Internally Generated TFSx/RFSx) <sup>3</sup>		4.0		3.0	ns
t <sub>HOFSI</sub>	TFSx/RFSx Hold After TSCLKx/RSCLKx (Internally Generated TFSx/RFSx) <sup>3</sup>	-2.0		-1.0		ns
t <sub>DDTI</sub>	Transmit Data Delay After TSCLKx <sup>3</sup>		4.0		3.0	ns
t <sub>HDTI</sub>	Transmit Data Hold After TSCLKx <sup>3</sup>	-1.8		-1.5		ns

 $<sup>^{\</sup>rm 1}$  Referenced to sample edge.

<sup>&</sup>lt;sup>2</sup>When SPORT is used in conjunction with the ACM, refer to the timing requirements in Table 41 (ACM Timing).

<sup>&</sup>lt;sup>3</sup> Referenced to drive edge.

<sup>&</sup>lt;sup>2</sup>When SPORT is used in conjunction with the ACM, refer to the timing requirements in Table 41 (ACM Timing).

 $<sup>^{\</sup>rm 3}\,\text{Referenced}$  to drive edge.

# Universal Asynchronous Receiver-Transmitter (UART) Ports—Receive and Transmit Timing

The UART ports receive and transmit operations are described in the *ADSP-BF50x Hardware Reference Manual*.

### **General-Purpose Port Timing**

Table 36 and Figure 25 describe general-purpose port operations.

Table 36. General-Purpose Port Timing

		$V_{DDEXT} = 1.8 V$		$V_{DDEXT} = 2.5 \text{ V}/3.3 \text{ V}$		
Parameter		Min	Max	Min	Max	Unit
Timing Requirement						
t <sub>WFI</sub> General-Purpose Port Pin Input Pulse Width		t <sub>SCLK</sub> + 1		t <sub>SCLK</sub> + 1		ns
Switching Characteristic						
$t_{GPOD}$	General-Purpose Port Pin Output Delay from CLKOUT High	0	11.0	0	8.9	ns

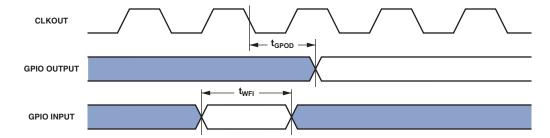


Figure 25. General-Purpose Port Timing

#### **ADC—TYPICAL PERFORMANCE CHARACTERISTICS**

 $T_A = 25$ °C, unless otherwise noted.

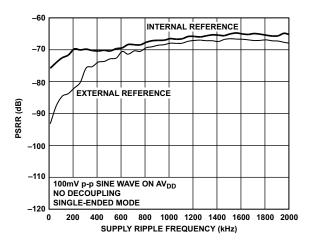


Figure 50. PSRR vs. Supply Ripple Frequency Without Supply Decoupling

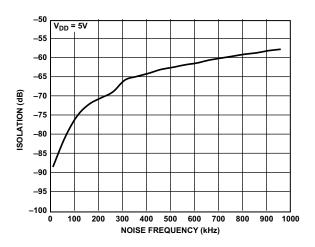


Figure 51. Channel-to-Channel Isolation

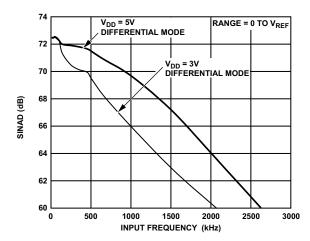


Figure 52. SINAD vs. Analog Input Frequency for Various Supply Voltages

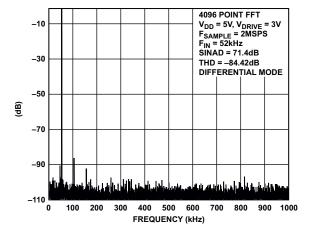


Figure 53. Typical FFT

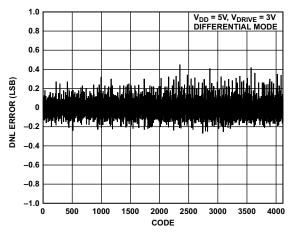


Figure 54. Typical DNL

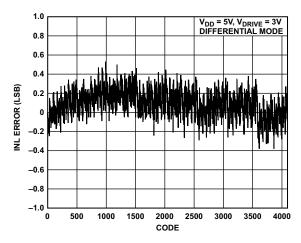


Figure 55. Typical INL

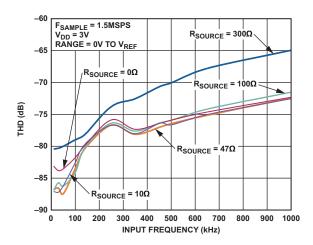


Figure 66. THD vs. Analog Input Frequency for Various Source Impedances, Differential Mode

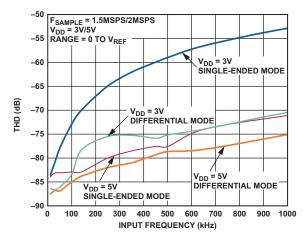


Figure 67. THD vs. Analog Input Frequency for Various Supply Voltages

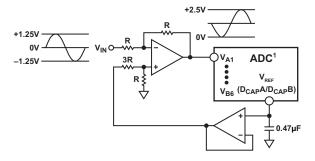
#### **Analog Inputs**

The ADC has a total of 12 analog inputs. Each on-board ADC has six analog inputs that can be configured as six single-ended channels, three pseudo differential channels, or three fully differential channels. These may be selected as described in the Analog Input Selection section.

#### Single-Ended Mode

The ADC can have a total of 12 single-ended analog input channels. In applications where the signal source has high impedance, it is recommended to buffer the analog input before applying it to the ADC. The analog input range can be programmed to be either 0 to  $V_{\text{REF}}$  or 0 to 2  $\times$   $V_{\text{REF}}.$ 

If the analog input signal to be sampled is bipolar, the internal reference of the ADC can be used to externally bias up this signal to make it correctly formatted for the ADC. Figure 68 shows a typical connection diagram when operating the ADC in single-ended mode.



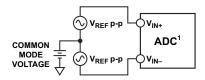
<sup>1</sup>ADDITIONAL PINS OMITTED FOR CLARITY.

Figure 68. Single-Ended Mode Connection Diagram

#### **Differential Mode**

The ADC can have a total of six differential analog input pairs.

Differential signals have some benefits over single-ended signals, including noise immunity based on the device's common-mode rejection and improvements in distortion performance. Figure 69 (Differential Input Definition) defines the fully differential analog input of the ADC.



<sup>1</sup>ADDITIONAL PINS OMITTED FOR CLARITY.

Figure 69. Differential Input Definition

The amplitude of the differential signal is the difference between the signals applied to the  $V_{\rm IN+}$  and  $V_{\rm IN-}$  pins in each differential pair  $(V_{\rm IN+}\,V_{\rm IN-}).\,V_{\rm IN+}$  and  $V_{\rm IN-}$  should be simultaneously driven by two signals each of amplitude  $V_{\rm REF}$  (or  $2\times V_{\rm REF}$ , depending on the range chosen) that are 180° out of phase. The amplitude of the differential signal is, therefore (assuming the 0 to  $V_{\rm REF}$  range is selected)  $-V_{\rm REF}$  to  $+V_{\rm REF}$  peak-to-peak  $(2\times V_{\rm REF})$ , regardless of the common mode (CM).

The common mode is the average of the two signals

$$(V_{IN+} + V_{IN-})/2$$

and is, therefore, the voltage on which the two inputs are centered.

This results in the span of each input being CM  $\pm$  V<sub>REF</sub>/2. This voltage has to be set up externally and its range varies with the reference value, V<sub>REF</sub>. As the value of V<sub>REF</sub> increases, the common-mode range decreases. When driving the inputs with an amplifier, the actual common-mode range is determined by the amplifier's output voltage swing.

Figure 70 (Input Common-Mode Range vs. VREF (0 to VREF Range, VDD = 5 V)) and Figure 71 (Input Common-Mode Range vs. VREF ( $2 \times VREF$  Range, VDD = 5 V)) show how the common-mode range typically varies with  $V_{REF}$  for a 5 V power

down for a relatively long duration between these bursts of several conversions. When the ADC is in partial power-down, all analog circuitry is powered down except for the on-chip reference and reference buffer.

To enter partial power-down mode, the conversion process must be interrupted by bringing  $\overline{CS}$  high anywhere after the second falling edge of ADSCLK and before the  $10^{th}$  falling edge of ADSCLK, as shown in Figure 81 (Entering Partial Power-Down Mode). Once  $\overline{CS}$  is brought high in this window of ADSCLKs, the part enters partial power-down, the conversion that was initiated by the falling edge of  $\overline{CS}$  is terminated, and  $D_{OUT}A$  and  $D_{OUT}B$  go back into three-state. If  $\overline{CS}$  is brought high before the second ADSCLK falling edge, the part remains in normal mode and does not power down. This avoids accidental power-down due to glitches on the  $\overline{CS}$  line.

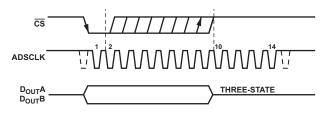


Figure 81. Entering Partial Power-Down Mode

To exit this mode of operation and power up the ADC again, a dummy conversion is performed. On the falling edge of  $\overline{CS}$ , the device begins to power up and continues to power up as long as  $\overline{CS}$  is held low until after the falling edge of the  $10^{th}$  ADSCLK. The device is fully powered up after approximately 1  $\mu$ s has elapsed, and valid data results from the next conversion, as shown in Figure 82 (Exiting Partial Power-Down Mode). If  $\overline{CS}$  is brought high before the second falling edge of ADSCLK, the ADC again goes into partial power-down. This avoids accidental power-up due to glitches on the  $\overline{CS}$  line. Although the device may begin to power up on the falling edge of  $\overline{CS}$ , it powers down

again on the rising edge of  $\overline{\text{CS}}$ . If the ADC is already in partial power-down mode and  $\overline{\text{CS}}$  is brought high between the second and 10<sup>th</sup> falling edges of ADSCLK, the device enters full power-down mode.

#### Full Power-Down Mode

This mode is intended for use in applications where throughput rates slower than those in the partial power-down mode are required, as power-up from a full power-down takes substantially longer than that from partial power-down. This mode is more suited to applications where a series of conversions performed at a relatively high throughput rate are followed by a long period of inactivity and thus power-down. When the ADC is in full power-down, all analog circuitry is powered down. Full power-down is entered in a similar way as partial power-down, except the timing sequence shown in Figure 81 (Entering Partial Power-Down Mode) must be executed twice. The conversion process must be interrupted in a similar fashion by bringing  $\overline{CS}$ high anywhere after the second falling edge of ADSCLK and before the 10<sup>th</sup> falling edge of ADSCLK. The device enters partial power-down at this point. To reach full power-down, the next conversion cycle must be interrupted in the same way, as shown in Figure 83 (Entering Full Power-Down Mode). Once CS is brought high in this window of ADSCLKs, the part completely powers down.

Note that it is not necessary to complete the 14 ADSCLKs once  $\overline{CS}$  is brought high to enter a power-down mode.

To exit full power-down and power up the ADC, a dummy conversion is performed, as when powering up from partial power-down. On the falling edge of  $\overline{CS}$ , the device begins to power up and continues to power up, as long as  $\overline{CS}$  is held low until after the falling edge of the  $10^{th}$  ADSCLK. The required power-up time must elapse before a conversion can be initiated, as shown in Figure 84 (Exiting Full Power-Down Mode). See the Power-Up Times section for the power-up times associated with the ADC.

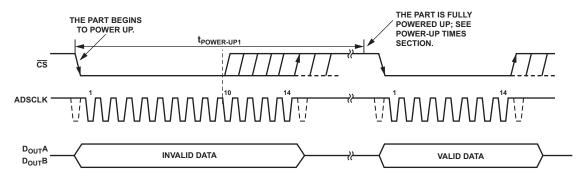
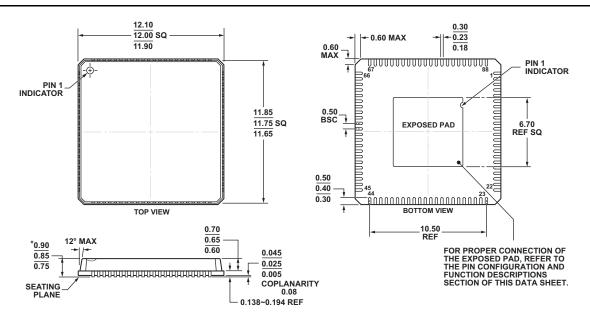


Figure 82. Exiting Partial Power-Down Mode



\*COMPLIANT TO JEDEC STANDARDS MO-220-VRRD EXCEPT FOR MINIMUM THICKNESS AND LEAD COUNT.

Figure 94. 88-Lead Lead Frame Chip Scale Package [LFCSP\_VQ]<sup>1</sup>
12 x 12 mm Body, Very Thin Quad
(CP-88-5)

Dimensions shown in millimeters

<sup>&</sup>lt;sup>1</sup> For information relating to the CP-88-5 package's exposed pad, see the table endnote on Page 76.

#### **AUTOMOTIVE PRODUCTS**

The ADBF504W model is available with controlled manufacturing to support the quality and reliability requirements of automotive applications. Note that these automotive models may have specifications that differ from the commercial models and designers should review the Specifications section of this

data sheet carefully. Only the automotive grade products shown in Table 58 are available for use in automotive applications. Contact your local ADI account representative for specific product ordering information and to obtain the specific Automotive Reliability reports for these models.

**Table 58. Automotive Products** 

Automotive Models <sup>1,2</sup>	Temperature Range <sup>3</sup>	Processor Instruction Rate (Maximum)		, <b>.</b> .	Package Option
ADBF504WYCPZ4XX	-40°C to +105°C	400 MHz	N/A	88-Lead LFCSP_VQ	CP-88-5

<sup>&</sup>lt;sup>1</sup> Z = RoHS compliant part.

### **ORDERING GUIDE**

Model <sup>1,2</sup>	Temperature Range <sup>3,4</sup>	Processor Instruction Rate (Maximum)	Flash Memory	Package Description	Package Option
ADSP-BF504BCPZ-3F	-40°C to +85°C	300 MHz	32M bit	88-Lead LFCSP_VQ	CP-88-5
ADSP-BF504BCPZ-4	-40°C to +85°C	400 MHz	N/A	88-Lead LFCSP_VQ	CP-88-5
ADSP-BF504BCPZ-4F	-40°C to +85°C	400 MHz	32M bit	88-Lead LFCSP_VQ	CP-88-5
ADSP-BF504KCPZ-3F	0°C to +70°C	300 MHz	32M bit	88-Lead LFCSP_VQ	CP-88-5
ADSP-BF504KCPZ-4	0°C to +70°C	400 MHz	N/A	88-Lead LFCSP_VQ	CP-88-5
ADSP-BF504KCPZ-4F	0°C to +70°C	400 MHz	32M bit	88-Lead LFCSP_VQ	CP-88-5
ADSP-BF506BSWZ-3F	-40°C to +85°C	300 MHz	32M bit	120-Lead LQFP_EP	SW-120-2
ADSP-BF506BSWZ-4F	-40°C to +85°C	400 MHz	32M bit	120-Lead LQFP_EP	SW-120-2
ADSP-BF506KSWZ-3F	0°C to +70°C	300 MHz	32M bit	120-Lead LQFP_EP	SW-120-2
ADSP-BF506KSWZ-4F	0°C to +70°C	400 MHz	32M bit	120-Lead LQFP_EP	SW-120-2

<sup>&</sup>lt;sup>1</sup> Z = RoHS compliant part.

<sup>&</sup>lt;sup>2</sup>The use of xx designates silicon revision.

<sup>&</sup>lt;sup>3</sup> Referenced temperature is ambient temperature. The ambient temperature is not a specification. Please see Operating Conditions on Page 26 for junction temperature (T<sub>j</sub>) specification which is the only temperature specification.

<sup>&</sup>lt;sup>2</sup> For feature comparison between ADSP-BF504, ADSP-BF504F, and ADSP-BF506F processors, see the Processor Comparison in Table 1 on Page 3.

<sup>&</sup>lt;sup>3</sup> Referenced temperature is ambient temperature. The ambient temperature is not a specification. Please see Operating Conditions on Page 26 for junction temperature (T<sub>j</sub>) specification which is the only temperature specification.

 $<sup>^4</sup>$ Temperature range  $0^{\circ}$ C to  $+70^{\circ}$ C is classified as commercial, and temperature range  $-40^{\circ}$ C to  $+85^{\circ}$ C is classified as industrial.